NSN 5961-01-329-4368

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View Online at https://aerobasegroup.com/nsn/5961-01-329-4368 **Inclosure Material:** Metal **Overall Length:** Between 1.188 inches and 1.252 inches **Overall Height:** Between 0.250 inches and 0.340 inches Overall Width: 0.700 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 80.0 collector to emitter voltage, dc with specified circuit between base and emitter and 6.0 emitter to base voltage, dc **Current Rating Per Characteristic:** 4.00 amperes source cutoff current and 2.00 amperes source cutoff current **Power Rating Per Characteristic:** 20.0 watts small-signal input power, common-collector absolute **Transfer Ratio:** 40.0 static forward current transfer ratio, common-emitter and 160.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius case **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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